Accepted Manuscript

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PII: S0925-8388(17)30526-1

DOI: 10.1016/j.jallcom.2017.02.088

Reference: JALCOM 40816

To appear in: Journal of Alloys and Compounds

Received Date: 9 November 2016

Revised Date: 1 January 2017

Accepted Date: 10 February 2017

Please cite this article as: M. Benkahoul, M.K. Zayed, A. Solieman, S.N. Alamri, Spray deposition of V_4O_9 and V_2O_5 thin films and post-annealing formation of thermochromic VO_2 , *Journal of Alloys and Compounds* (2017), doi: 10.1016/j.jallcom.2017.02.088.

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Spray deposition of V_4O_9 and V_2O_5 thin films and post-annealing formation of thermochromic VO_2

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Abstract

Vanadium oxide (VO_x) thin films were deposited at various substrate temperatures (T_s) by spray pyrolysis technique using 0.05 M vanadyl acetylacetonate precursor. V₄O₉ films are formed at $T_s = 300^{\circ}$ C, while mixed V₂O₅ phases are formed at higher T_s (400 and 500°C). Annealing in forming gas of V₄O₉ films shows the formation of higher content of thermochromic VO₂ phase than V₂O₅ films. V₄O₉ films show little higher electric resistivity (ρ), higher temperature coefficient of resistance (*TCR*), and higher thermal carrier activation energy (E_a) than V₂O₅ films. Annealed VO_x films show a 2-3 order of magnitude change in ρ , optical transmission switch of 19-39%, and higher E_a than to the as deposited films. Annealed films deposited at T_s =500°C presents a high *TCR* of -4.6% K⁻¹. Optical absorption, electronic transitions, and energy gaps of the formed VO_x phases have been discussed in relation to its electronic band structure.

Keywords: Vanadium oxide, V_4O_9 , V_2O_5 , spray pyrolysis, thermochromic, annealing, thin films, electric and optical properties

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